## NSN 5961-00-138-1135

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-138-1135 **Inclosure Material:** Plastic **Overall Length:** Between 0.280 inches and 0.320 inches **Overall Height:** Between 0.175 inches and 0.185 inches **Overall Width:** Between 0.240 inches and 0.260 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 breakover voltage, dc **Current Rating Per Characteristic:** 4.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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